NSN 5961-00-999-0490

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-999-0490 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.105 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 6.50 milliamperes forward current, dc **Power Rating Per Characteristic:** 500.00 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Nuclear Hardness Critical Feature:** Hardened **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

Fiig:

A110a0